



Surface Mount General Purpose Rectifier

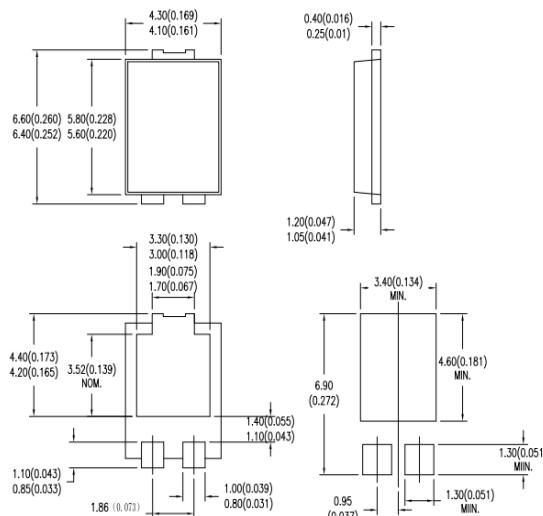
Features

- Low profile package
- Ideal for automated placement
- Glass passivated chip junction
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C



TO-277B

Cathode & Heatsink Anode 1 Anode 2



Typical Applications

For use in general purpose rectification of power supplies, inverters, converters, and freewheeling diodes for consumer, and telecommunication.

Mechanical Data

Case: TO-277B

Molding compound meets UL 94 V-0 flammability rating

Moisture sensitivity level: level 1, per J-STD-020

Terminal: Matte tin plated leads, solderable per JESD22-B102

Meet JESD 201 class 2 whisker test

Polarity: Indicated by cathode band

Weight: 0.095g (approximately)

■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	S5A	S5B	S5D	S5G	S5J	S5K	S5M
Maximum Repetitive peak reverse voltage	V _{RRM}	V	50	100	200	400	600	800	1000
Maximum RMS Voltage	V _{RMS}	V	35	70	140	280	420	560	700
Maximum DC Blocking Voltage	V _{DC}	V	50	100	200	400	600	800	1000
Average Rectified Output Current @60Hz sine wave, Resistance load, TL (FIG.1)	I _O	A					5.0		
Forward Surge Current (Non-repetitive) @60Hz Half-sine wave, 1 cycle, Tj=25°C	I _{FSR}	A					150		
Forward Surge Current (Non-repetitive) @1ms, square wave, 1 cycle, Tj=25°C	I _{FSM}	A					300		
Current squared time @1ms≤t≤8.3ms Tj=25°C	I ² t	A ² s					94		
Storage Temperature	T _{stg}	°C					-55 ~ +150		
Junction Temperature	T _j	°C					-55 ~ +150		



■ Electrical Characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	S5A	S5B	S5D	S5G	S5J	S5K	S5M
Maximum instantaneous forward voltage	VF	V	IFM=5.0A							1.1
Maximum DC reverse current at rated DC blocking voltage	IR	μA	$T_j=25^\circ\text{C}$							5
			$T_j=125^\circ\text{C}$							100
Typical junction capacitance	C _j	pF	Measured at 1MHz and Applied Reverse Voltage of 4.0 V.D.C							33

■ Thermal Characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	S5A	S5B	S5D	S5G	S5J	S5K	S5M
Typical Thermal resistance	R _{θJ-A}	$^\circ\text{C}/\text{W}$							48
	R _{θJ-L}								15
	R _{θJ-C}								12

Note(1)

Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.6" x 0.6" (16 mm x 16 mm) copper pad areas

■ Characteristics(Typical)

FIG.1: Io-TL Curve

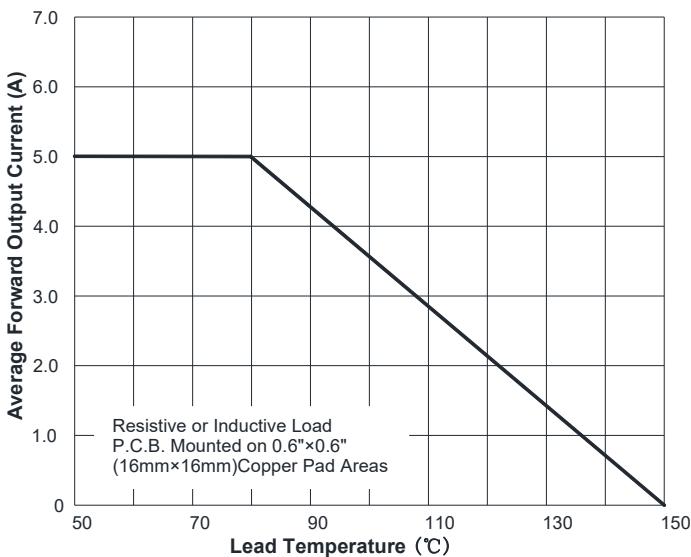


FIG.2: Forward Surge Current Capability

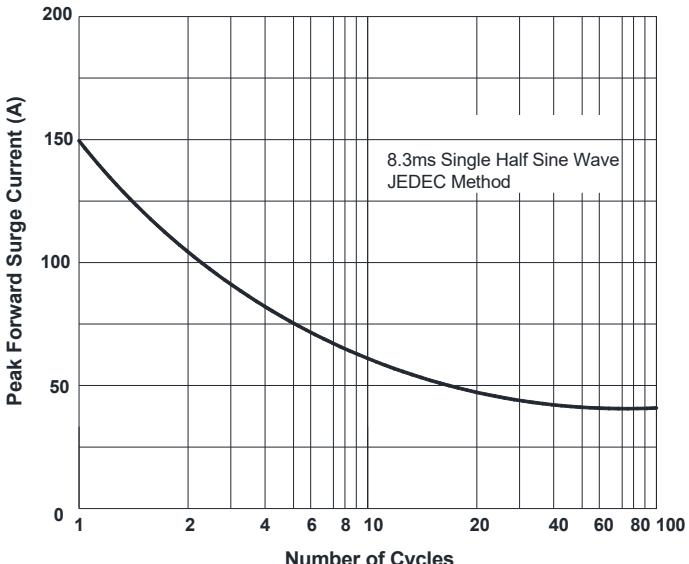


FIG.3: Typical Forward Voltage

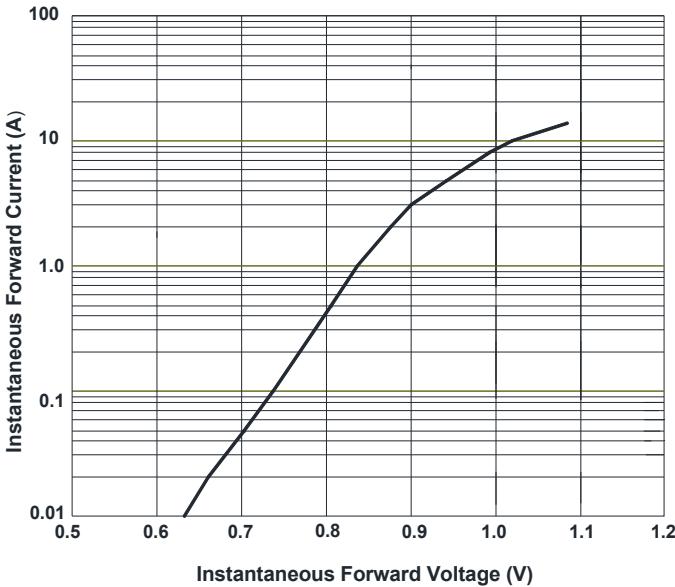


FIG.4: Typical Reverse Characteristics

